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Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 8 A



1200 V

3.3 V

8 A

28 ns

150 °C

140 nC

85 A/µs

4.5 A

Base

N/C

PRODUCT SUMMARY

 V_{R}

V_F at 8 A at 25 °C

I_{F(AV)}

trr (typical)

T_J (maximum)

Q_{rr} (typical)

dI(rec)M/dt (typical) at 125 °C

I_{RRM} (typical)

2

D²PAK

Anode



- Ultrafast recovery Ultrasoft recovery
- Very low I_{BBM}

FEATURES

- Very low Q_{rr}
- · Specified at operating conditions
- · Designed and qualified for industrial level

BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- · Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA08TB120S is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 8 A continuous current, the HFA08TB120S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08TB120S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		1200	V	
Maximum continuous forward current	۱ _F	T _C = 100 °C	8		
Single pulse forward current	I _{FSM}		130	А	
Maximum repetitive forward current	I _{FRM}		32		
Maximum power dissipation	$T_{\rm C} = 25 ^{\circ}{\rm C}$	73.5	w		
	PD	T _C = 100 °C	29	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

* Pb containing terminations are not RoHS compliant, exemptions may apply

HFA08TB120S



Vishay High Power Products HEXFRED[®] Ultrafast Soft Recovery Diode, 8 A

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-	
		I _F = 8.0 A	-	2.6	3.3	v
Maximum forward voltage	V _{FM}	I _F = 16 A	-	3.4	4.3	
		I _F = 8.0 A, T _J = 125 °C	-	2.4	3.1	
Maximum reverse		$V_{\rm R} = V_{\rm R}$ rated	-	0.31	10	
leakage current	IRM	T_J = 125 °C, V_R = 0.8 x V_R rated	-	135	1000	μΑ
Junction capacitance	CT	V _R = 200 V	-	11	20	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ J}$	A, $dI_F/dt = 200 \text{ A}/\mu \text{s}$, $V_R = 30 \text{ V}$		28	-	
Reverse recovery time	t _{rr1}	T _J = 25 °C		-	63	95	ns
	t _{rr2}	T _J = 125 °C	I _F = 8.0 A dI _F /dt = 200 A/μs V _R = 200 V	-	106	160	
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	4.5	8.0	A
	I _{RRM2}	T _J = 125 °C		-	6.2	11	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	140	380	nC
	Q _{rr2}	T _J = 125 °C		-	335	880	
Peak rate of fall of recovery current during t _b	dl _{(rec)M} /dt1	T _J = 25 °C		-	133	-	A/µs
	dI _{(rec)M} /dt2	T _J = 125 °C		-	85	-	Λμο

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	1.7	K/W
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	- r./ v v
Weight			-	2.0	-	g
		-	0.07	-	oz.	
Marking device		Case style D ² PAK		HFA08	TB120S	-

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95046				
Part marking information	http://www.vishay.com/doc?95054			
Packaging information http://www.vishay.com/doc?95032				



Vishay

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